INTEGRATED CIRCUITS



Product specification Supersedes data of 1996 Mar 05 IC23 Data Handbook

1998 Jan 16



PHILIPS

Philips Semiconductors

74ABT125

FEATURES

- Quad bus interface
- 3-State buffers
- Live insertion/extraction permitted
- Output capability: +64mA/–32mA
- Latch-up protection exceeds 500mA per Jedec Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model
- Power-up 3-State
- Inputs are disabled during 3-State mode

QUICK REFERENCE DATA

DESCRIPTION

The 74ABT125 high-performance BiCMOS device combines low static and dynamic power dissipation with high speed and high output drive.

The 74ABT125 device is a quad buffer that is ideal for driving bus lines. The device features four Output Enables ($\overline{OE0}$, $\overline{OE1}$, $\overline{OE2}$, $\overline{OE3}$), each controlling one of the 3-State outputs.

SYMBOL	PARAMETER	PARAMETERCONDITIONS $T_{amb} = 25^{\circ}C; GND = 0V$			
t _{PLH} t _{PHL}	Propagation delay An to Yn	$C_L = 50 pF; V_{CC} = 5V$	2.9	ns	
C _{IN}	Input capacitance	$V_{I} = 0V \text{ or } V_{CC}$	4	pF	
C _{OUT}	Output capacitance	Outputs disabled; $V_O = 0V$ or V_{CC}	7	pF	
I _{CCZ}	Total supply current	Outputs disabled; V _{CC} =5.5V	65	μΑ	

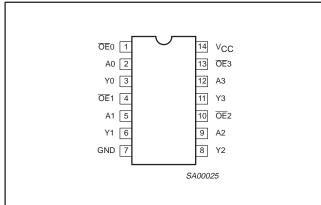
ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
14-Pin Plastic DIP	-40°C to +85°C	74ABT125 N	74ABT125 N	SOT27-1
14-Pin plastic SO	-40°C to +85°C	74ABT125 D	74ABT125 D	SOT108-1
14-Pin Plastic SSOP Type II	-40°C to +85°C	74ABT125 DB	74ABT125 DB	SOT337-1
14-Pin Plastic TSSOP Type I	-40°C to +85°C	74ABT125 PW	74ABT125PW DH	SOT402-1

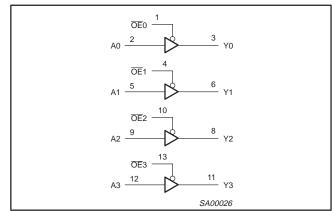
PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
2, 5, 9, 12	A0 – A3	Data inputs
3, 6, 8, 11	Y0 – Y3	Data outputs
1, 4, 10, 13	OE0 – OE3	Output enable inputs (active-Low)
7	GND	Ground (0V)
14	V _{CC}	Positive supply voltage

PIN CONFIGURATION



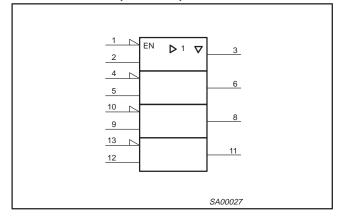
LOGIC SYMBOL



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74ABT125

LOGIC SYMBOL (IEEE/IEC)



FUNCTION TABLE

INPU	OUTPUTS	
OEn	An	Yn
L	L	L
L	Н	Н
Н	Х	Z

H = High voltage level

L = Low voltage level

X = Don't care Z = High impedance "off" state

ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		–0.5 to +7.0	V
I _{IK}	DC input diode current	V ₁ < 0	-18	mA
VI	DC input voltage ³		-1.2 to +7.0	V
I _{ОК}	DC output diode current	V _O < 0	-50	mA
V _{OUT}	DC output voltage ³	output in Off or High state	-0.5 to +5.5	V
I _{OUT}	DC output current	output in Low state	128	mA
T _{stg}	Storage temperature range		-65 to 150	°C

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction 2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	UNIT	
STWBOL	PARAMETER	MIN	MAX	UNIT
V _{CC}	DC supply voltage	4.5	5.5	V
VI	Input voltage	0	V _{CC}	V
V _{IH}	High-level input voltage	2.0		V
VIL	Low-level input voltage		0.8	V
I _{OH}	High-level output current		-32	mA
I _{OL}	Low-level output current	64		mA
$\Delta t/\Delta v$	Input transition rise or fall rate	0	10	ns/V
T _{amb}	Operating free-air temperature range	-40	+85	°C

Product specification

74ABT125

DC ELECTRICAL CHARACTERISTICS

				LIMITS					
SYMBOL	PARAMETER	TEST CONDITIONS	T _{amb} = +25°C			T _{amb} = −40°C to +85°C			
			Min	Тур	Max	Min	Max	1	
V _{IK}	Input clamp voltage	$V_{CC} = 4.5V; I_{IK} = -18mA$		-0.9	-1.2		-1.2	V	
		V_{CC} = 4.5V; I_{OH} = –3mA; V_{I} = V_{IL} or V_{IH}	2.5	2.9		2.5		V	
V _{OH}	High-level output voltage	V_{CC} = 5.0V; I_{OH} = –3mA; V_{I} = V_{IL} or V_{IH}	3.0	3.4		3.0		V	
		V_{CC} = 4.5V; I_{OH} = –32mA; V_{I} = V_{IL} or V_{IH}	2.0	2.4		2.0		V	
V _{OL}	Low-level output voltage	V_{CC} = 4.5V; I_{OL} = 64mA; V_{I} = V_{IL} or V_{IH}		0.35	0.55		0.55	V	
l	Input leakage current	V_{CC} = 5.5V; V_I = GND or 5.5V		±0.01	±1.0		±1.0	μA	
I _{OFF}	Power-off leakage current	V_{CC} = 0.0V; V_{O} or $V_{I}\ \leq 4.5V$		±5.0	±100		±100	μA	
I _{PU} /I _{PD}	Power-up/down 3-State output current ³	V_{CC} = 2.1V; V_{O} = 0.5V; V_{I} GND or V_{CC} ; V_{OE} = Don't care		±5.0	±50		±50	μΑ	
I _{OZH}	3-State output High current	V_{CC} = 5.5V; V_{O} = 2.7V; V_{I} = V_{IL} or V_{IH}		1.0	50		50	μA	
I _{OZL}	3-State output Low current	V_{CC} = 5.5V; V_{O} = 0.5V; V_{I} = V_{IL} or V_{IH}		-1.0	-50		-50	μA	
I _{CEX}	Output High leakage current	V_{CC} = 5.5V; V_{O} = 5.5V; V_{I} = GND or V_{CC}		5.0	50		50	μA	
Ι _Ο	Output current ¹	$V_{CC} = 5.5V; V_{O} = 2.5V$	-50	-100	-180	-50	-180	mA	
I _{CCH}		V_{CC} = 5.5V; Outputs High, V_{I} = GND or V_{CC}		65	250		250	μA	
I _{CCL}	Quiescent supply current	V_{CC} = 5.5V; Outputs Low, V_I = GND or V_{CC}		12	15		30	mA	
I _{CCZ}		V_{CC} = 5.5V; Outputs 3–State; V _I = GND or V _{CC}		65	250		50	μΑ	
		Outputs enabled, one data input at 3.4V, other inputs at V _{CC} or GND; V_{CC} = 5.5V		0.5	1.5		1.5	mA	
ΔI_{CC}	Additional supply current per input pin ²	Outputs 3-State, one data input at 3.4V, other inputs at V _{CC} or GND; V _{CC} = 5.5V		50	250		250	μΑ	
		Outputs 3-State, one enable input at 3.4V, other inputs at V_{CC} or GND; $V_{CC} = 5.5V$		0.5	1.5		1.5	mA	

NOTES:

1. Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

2. This is the increase in supply current for each input at 3.4V. 3. This parameter is valid for any V_{CC} between 0V and 2.1V, with a transition time of up to 10msec. From V_{CC} = 2.1V to V_{CC} = 5V \pm 10% a transition time of up to 100µsec is permitted.

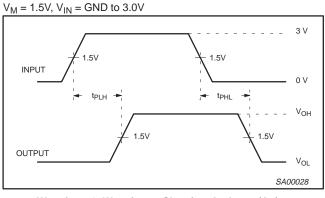
AC CHARACTERISTICS

GND = 0V; $t_R = t_F$ = 2.5ns; C_L = 50pF, R_L = 500 Ω

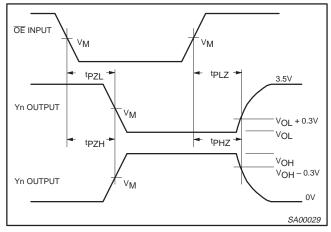
					LIMIT	ſS		
SYMBOL	PARAMETER	WAVEFORM	T _{amb} = +25°C V _{CC} = +5.0V			$T_{amb} = -40^{\circ}$ $V_{CC} = +5^{\circ}$	UNIT	
			MIN	ТҮР	MAX	MIN	MAX	
t _{PLH} t _{PHL}	Propagation delay An to Yn	1	1.0 1.0	2.8 3.1	4.1 4.6	1.0 1.0	4.6 4.9	ns
t _{PZH} t _{PZL}	Output enable time to High and Low level	2	1.0 1.0	3.2 4.2	5.0 6.2	1.0 1.0	5.9 6.8	ns
t _{PHZ} t _{PLZ}	Output disable time from High and Low level	2	1.0 1.5	4.1 2.8	5.4 5.0	1.0 1.5	6.2 5.5	ns

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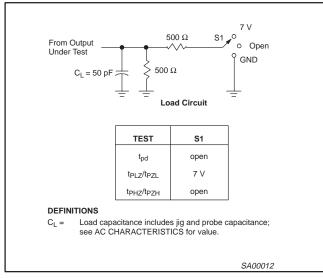
AC WAVEFORMS



Waveform 1. Waveforms Showing the Input (An) to Output (Yn) Propagation Delays



Waveform 2. Waveforms Showing the 3-State Output Enable and Disable Times

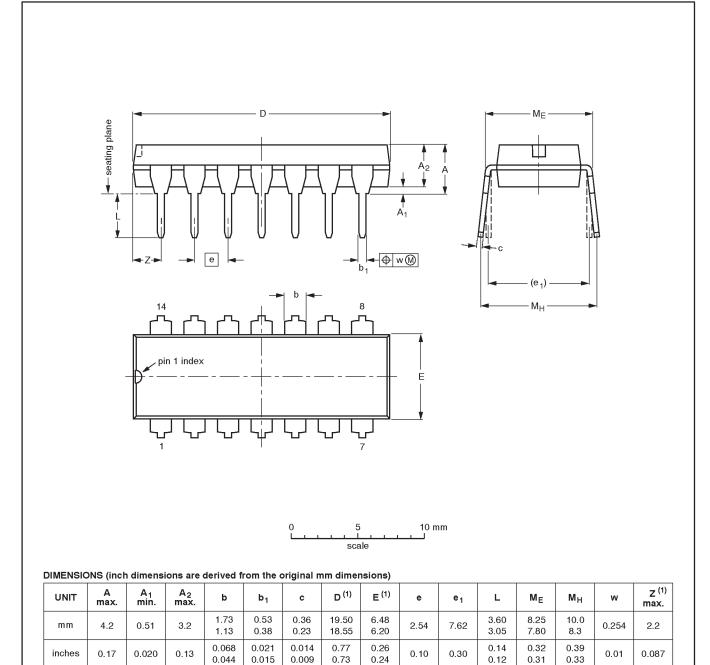


TEST CIRCUIT AND WAVEFORMS

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DIP14: plastic dual in-line package; 14 leads (300 mil)



1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

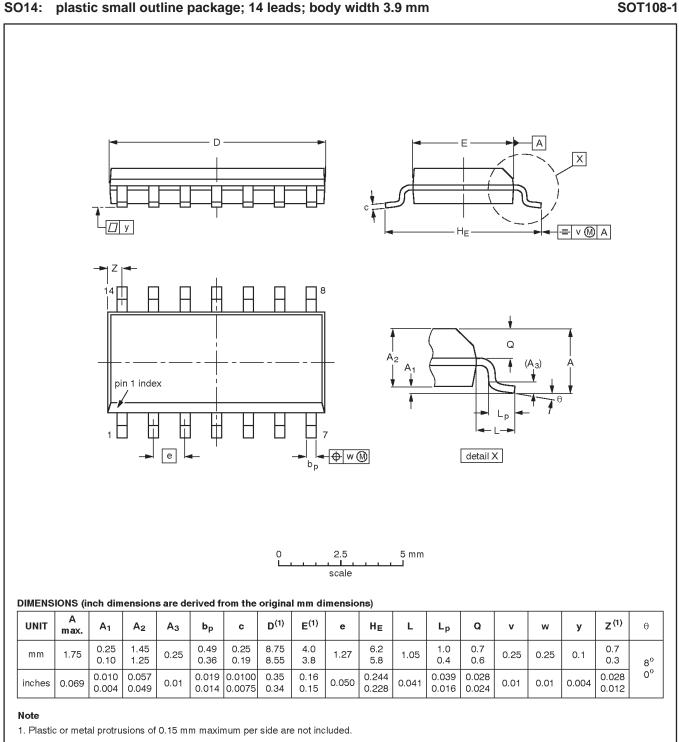
OUTLINE		REFERENCES				ISSUE DATE
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT27-1	050G04	MO-001AA				-92-11-17 95-03-11

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SOT27-1

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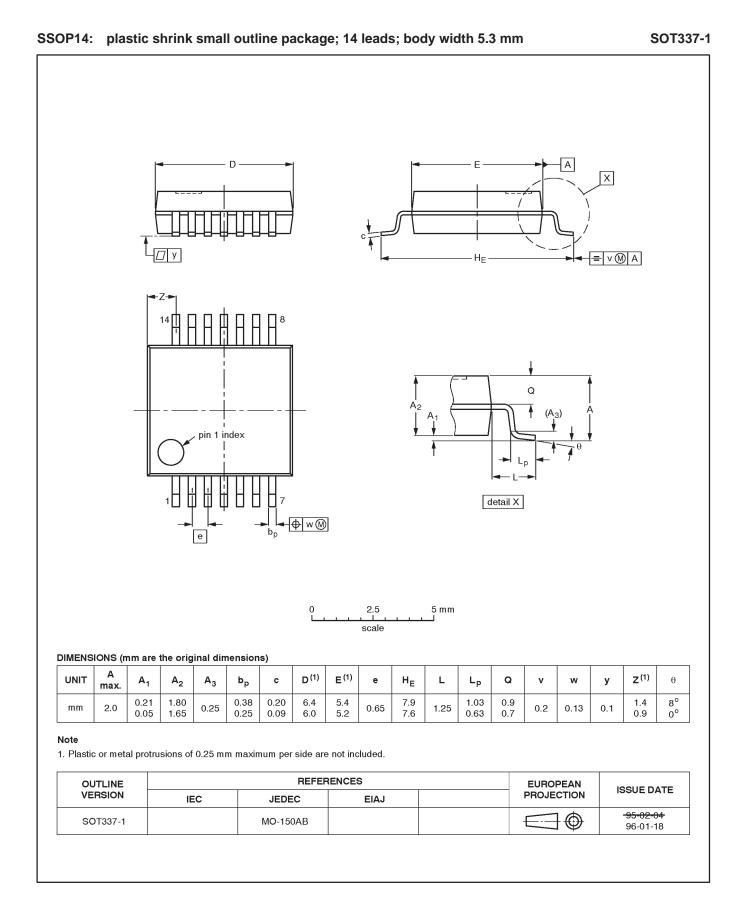


OUTLINE	REFERENCES			EUROPEAN ISSUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT108-1	076E06S	MS-012AB				-95-01-23 97-05-22

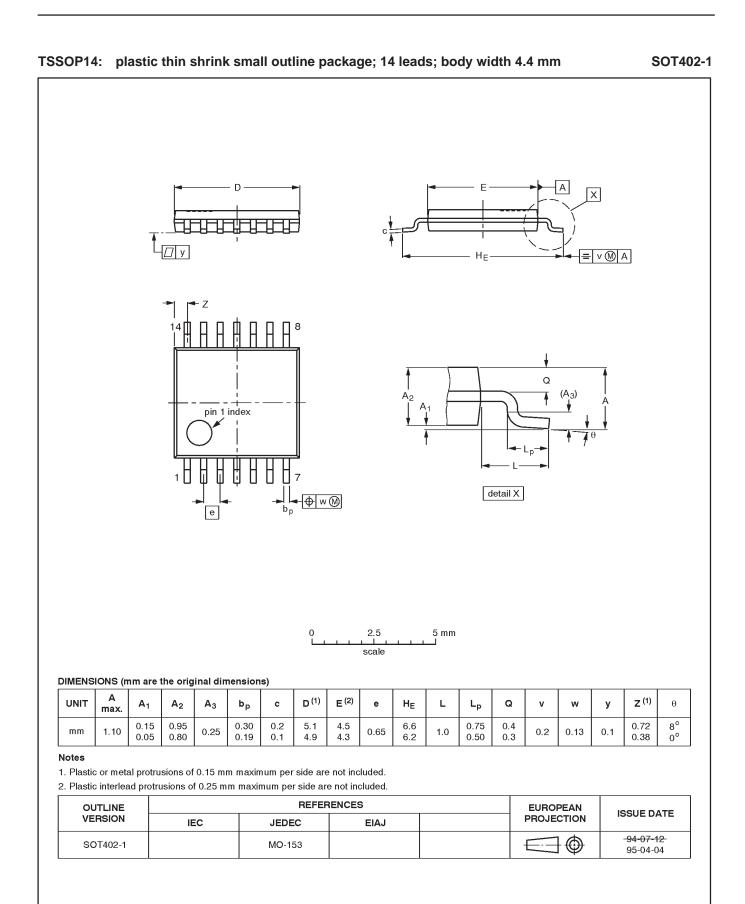
SO14: plastic small outline package; 14 leads; body width 3.9 mm

Product specification

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DEFINITIONS				
Data Sheet Identification Product Status Definition		Definition		
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.		
Preliminary Specification Preproduction Product		This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.		
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